# Low-Voltage Single SPDT MICRO FOOT® Analog Switch

## DESCRIPTION

The DG3000 is a single-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed ($t_{ON}$: 24 ns, $t_{OFF}$: 9 ns), low on-resistance ($r_{DS(on)}$: 1.4 Ω) and small physical size (MICRO FOOT, 6-bump), the DG3000 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG3000 is built on Vishay Siliconix's low voltage JI2 process. An epitaxial layer prevents latchup. Break-before - make is guaranteed for DG3000.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For MICRO FOOT analog switching products manufactured with tin/ silver/copper (Sn/Ag/Cu) device terminations, the lead (Pb)-free "-E1" suffix is being used as a designator.

## FEATURES

- MICRO FOOT® Chip Scale Package (1.07 x 1.57 mm)
- Low Voltage Operation (1.8 V to 5.5 V)
- Low On-Resistance - $r_{DS(on)}$: 1.4 Ω
- Fast Switching - $t_{ON}$: 24 ns, $t_{OFF}$: 9 ns
- Low Power Consumption
- TTL/CMOS Compatible

Pb-free Available

RoHS* COMPLIANT

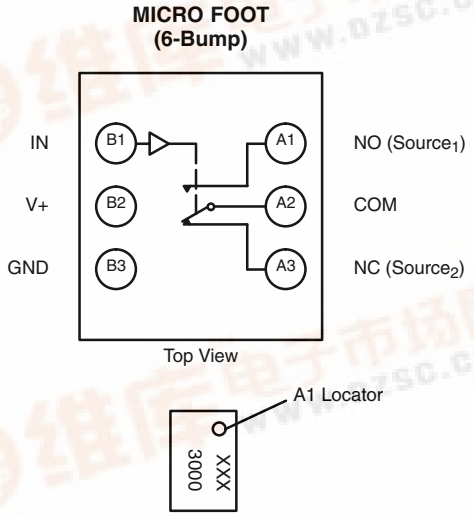
## BENEFITS

- Reduced Power Consumption
- Simple Logic Interface
- High Accuracy
- Reduce Board Space

## APPLICATIONS

- Cellular Phones
- Communication Systems
- Portable Test Equipment
- Battery Operated Systems
- PCM Cards
- PDA

## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION




**Device Marking:** 3000
xxx = Date/Lot Traceability Code

| TRUTH TABLE | | |
|---|---|---|
| **Logic** | **NC** | **NO** |
| 0 | ON | OFF |
| 1 | OFF | ON |

| ORDERING INFORMATION | | |
|---|---|---|
| **Temp Range** | **Package** | **Part Number** |
| - 40 to 85 °C | MICRO FOOT: 6-Bump<br>3 x 2, 0.5 mm Pitch<br>165 µm nom. bump height<br>(Eutectic, SnPb) | DG3000DB-T1 |
| | MICRO FOOT: 6-Bump<br>3 x 2, 0.5 mm pitch,<br>238 µm nom. bump height<br>(Lead (Pb)-free, Sn/Ag/Cu) | DG3000DB-T1-E1 |

* Pb containing terminations are not RoHS compliant, exemptions may apply.

| **ABSOLUTE MAXIMUM RATINGS** $T_A$ = 25 °C, unless otherwise noted | | | |
|---|---|---|---|
| **Parameter** | | **Limit** | **Unit** |
| Referenced V+ to GND | | - 0.3 to + 6 V | V |
| IN, COM, NC, NO[a] | | - 0.3 V to (V+ + 0.3 V) | |
| Continuous Current (Any Terminal) | | ± 50 | mA |
| Peak Current (Pulsed at 1 ms, 10 % duty cycle) | | ± 200 | |
| Storage Temperature (D Suffix) | | - 65 to 150 | °C |
| **Package Reflow Conditions[b]** | | | |
| VPR (Eutectic) | | 215 | °C |
| IR/Convection (Eutectic) | | 220 | |
| IR/Convection (Lead (Pb)-free) | | 250 | |
| Power Dissipation (Packages)[c] | 6-Bump, 3 x 2 MICRO FOOT[d] | 250 | mW |

Notes:
a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. Refer to IPC/JEDEC (J-STD-020A). No hand/manual solder rework recommended.
c. All bumps soldered to PC Board.
d. Derate 3.1 mW/°C above 70 °C.

| **SPECIFICATIONS (V+ = 2.0 V)** | | | | | | | |
|---|---|---|---|---|---|---|---|
| | | **Test Conditions Otherwise Unless Specified** | | **Limits** - 40 to 85 °C | | | |
| **Parameter** | **Symbol** | V+ = 2.0 V, ± 10 %, $V_{IN}$ = 0.4 or 1.6 V[e] | **Temp[a]** | **Min[b]** | **Typ[c]** | **Max[b]** | **Unit** |
| **Analog Switch** | | | | | | | |
| Analog Signal Range[d] | $V_{NO}$, $V_{NC}$ $V_{COM}$ | | Full | 0 | | V+ | V |
| On-Resistance | $r_{ON}$ | V+ = 1.8 V, $V_{COM}$ = 1.0 V, $I_{NO}$, $I_{NC}$ = 10 mA | Room<br>Full[d] | | 17 | 20<br>22.5 | Ω |
| $r_{ON}$ Flatness[d] | $r_{ON}$ Flatness | V+ = 1.8 V, $V_{COM}$ = 0 to V+, $I_{NO}$, $I_{NC}$ = 10 mA | Room | | 14 | | |
| Switch Off Leakage Current[f] | $I_{NO(off)}$<br>$I_{NC(off)}$ | V+ = 2.2 V<br>$V_{NO}$, $V_{NC}$ = 0.5 V/1.5 V, $V_{COM}$ = 1.5 V/0.5 V | Room<br>Full[d] | - 700<br>- 11 | | 700<br>11 | pA<br>nA |
| | $I_{COM(off)}$ | | Room<br>Full[d] | - 700<br>- 11 | | 700<br>11 | pA<br>nA |
| Channel-On Leakage Current[f] | $I_{COM(on)}$ | V+ = 2.2 V, $V_{NO}$, $V_{NC}$ = $V_{COM}$ = 0.5 V/1.5 V | Room<br>Full[d] | - 700<br>- 11 | | 700<br>11 | pA<br>nA |
| **Digital Control** | | | | | | | |
| Input High Voltage | $V_{INH}$ | | Full | 1.6 | | | V |
| Input Low Voltage | $V_{INL}$ | | Full | | | 0.4 | |
| Input Capacitance[d] | $C_{in}$ | | Full | | 5 | | pF |
| Input Current[d] | $I_{INL}$ or $I_{INH}$ | $V_{IN}$ = 0 or V+ | Full | - 1 | | 1 | µA |
| **Dynamic Characteristics** | | | | | | | |
| Turn-On Time | $t_{ON}$ | $V_{NO}$ or $V_{NC}$ = 1.5 V, $R_L$ = 300 Ω, $C_L$ = 35 pF<br>Figures 1 and 2 | Room<br>Full[d] | | 61 | 76<br>79 | ns |
| Turn-Off Time | $t_{OFF}$ | | Room<br>Full[d] | | 17 | 33<br>36 | |
| Break-Before-Make Time | $t_d$ | | Room | 1 | 45 | | |
| Charge Injection[d] | $Q_{INJ}$ | $C_L$ = 1 nF, $V_{GEN}$ = 0 V, $R_{GEN}$ = 0 Ω, Figure 3 | Room | | 2 | | pC |
| Off-Isolation[d] | OIRR | $R_L$ = 50 Ω, $C_L$ = 5 pF, f = 1 MHz | Room | | - 61 | | dB |
| Crosstalk[d] | $X_{TALK}$ | | Room | | - 67 | | |
| NO, NC Off Capacitance[d] | $C_{NO(off)}$<br>$C_{NC(off)}$ | $V_{IN}$ = 0 or V+, f = 1 MHz | Room | | 31 | | pF |
| Channel-On Capacitance[d] | $C_{ON}$ | | Room | | 98 | | |
| **Power Supply** | | | | | | | |
| Power Supply Range | V+ | | | 1.8 | | 2.2 | V |
| Power Supply Current[d] | I+ | $V_{IN}$ = 0 or V+ | | | 0.1 | 1.0 | µA |
| Power Consumption | $P_C$ | | | | | 2.2 | µW |

## SPECIFICATIONS (V+ = 3.0 V)

| Parameter | Symbol | Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, $V_{IN}$ = 0.4 or 2.0 V[e] | Temp[a] | Limits - 40 to 85 °C Min[b] | Typ[c] | Max[b] | Unit |
|---|---|---|---|---|---|---|---|
| **Analog Switch** | | | | | | | |
| Analog Signal Range[d] | $V_{NO}$, $V_{NC}$ $V_{COM}$ | | Full | 0 | | V+ | V |
| On-Resistance[d] | $r_{ON}$ | V+ = 2.7 V, $V_{COM}$ = 1.5 V, $I_{NO}$, $I_{NC}$ = 10 mA | Room<br>Full | | 3.3<br>3.4 | 4.1<br>4.2 | Ω |
| $r_{ON}$ Flatness[d] | $r_{ON}$ Flatness | V+ = 2.7 V, $V_{COM}$ = 0 to V+, $I_{NO}$, $I_{NC}$ = 10 mA | Room | | 1.3 | | Ω |
| Switch Off Leakage Current[f] | $I_{NO(off)}$<br>$I_{NC(off)}$ | V+ = 3.3 V<br>$V_{NO}$, $V_{NC}$ = 1 V/3 V, $V_{COM}$ = 3 V/1 V | Room<br>Full | - 800<br>- 13 | | 800<br>13 | pA<br>nA |
| | $I_{COM(off)}$ | | Room<br>Full | - 800<br>- 13 | | 800<br>13 | pA<br>nA |
| Channel-On Leakage Current[f] | $I_{COM(on)}$ | V+ = 3.3 V, $V_{NO}$, $V_{NC}$ = $V_{COM}$ = 1 V/3 V | Room<br>Full | - 800<br>- 13 | | 800<br>13 | pA<br>nA |
| **Digital Control** | | | | | | | |
| Input High Voltage | $V_{INH}$ | | Full | 2 | | | V |
| Input Low Voltage | $V_{INL}$ | | Full | | | 0.4 | V |
| Input Capacitance[d] | $C_{in}$ | | Full | | 5 | | pF |
| Input Current[d] | $I_{INL}$ or $I_{INH}$ | $V_{IN}$ = 0 or V+ | Full | - 1 | | 1 | µA |
| **Dynamic Characteristics** | | | | | | | |
| Turn-On Time[d] | $t_{ON}$ | $V_{NO}$ or $V_{NC}$ = 2.0 V, $R_L$ = 300 Ω, $C_L$ = 35 pF Figures 1 and 2 | Room<br>Full | | 34 | 49<br>52 | ns |
| Turn-Off Time[d] | $t_{OFF}$ | | Room<br>Full | | 12 | 30<br>33 | ns |
| Break-Before-Make Time[d] | $t_d$ | | Room | 1 | 23 | | ns |
| Charge Injection[d] | $Q_{INJ}$ | $C_L$ = 1 nF, $V_{GEN}$ = 0 V, $R_{GEN}$ = 0 Ω, Figure 3 | Room | | 4 | | pC |
| Off-Isolation[d] | OIRR | $R_L$ = 50 Ω, $C_L$ = 5 pF, f = 1 MHz | Room | | - 61 | | dB |
| Crosstalk[d] | $X_{TALK}$ | | Room | | - 67 | | dB |
| NO, NC Off Capacitance[d] | $C_{NO(off)}$<br>$C_{NC(off)}$ | $V_{IN}$ = 0 or V+, f = 1 MHz | Room | | 31 | | pF |
| Channel-On Capacitance[d] | $C_{ON}$ | | Room | | 47 | | pF |
| **Power Supply** | | | | | | | |
| Power Supply Range | V+ | | | 2.7 | | 3.3 | V |
| Power Supply Current[d] | I+ | $V_{IN}$ = 0 or V+ | | | 0.1 | 1.0 | µA |
| Power Consumption | $P_C$ | | | | | 3.3 | µW |

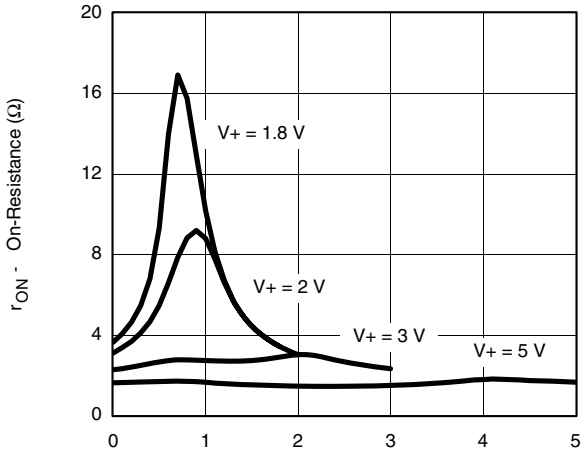
## SPECIFICATIONS (V+ = 5.0 V)

| Parameter | Symbol | Test Conditions Otherwise Unless Specified V+ = 5 V, ± 10 %, $V_{IN}$ = 0.8 or 2.4 V[e] | Temp[a] | Limits - 40 to 85 °C Min[b] | Typ[c] | Max[b] | Unit |
|---|---|---|---|---|---|---|---|
| **Analog Switch** | | | | | | | |
| Analog Signal Range[d] | $V_{NO}$, $V_{NC}$ $V_{COM}$ | | Full | 0 | | V+ | V |
| On- Resistance | $r_{ON}$ | V+ = 4.5 V, $V_{COM}$ = 3 V, $I_{NO}$, $I_{NC}$ = 10 mA | Room<br>Full | | 1.4<br>1.6 | 2.3<br>2.8 | Ω |
| $r_{ON}$ Flatness[d] | $r_{ON}$ Flatness | V+ = 4.5 V, $V_{COM}$ = 0 to V+, $I_{NO}$, $I_{NC}$ = 10 mA | Room | | 0.5 | | Ω |
| Switch Off Leakage Current | $I_{NO(off)}$ $I_{NC(off)}$ | V+ = 5.5 V<br>$V_{NO}$, $V_{NC}$ = 1 V/4.5 V, $V_{COM}$ = 4.5 V/1 V | Room<br>Full | - 1.2<br>- 21 | | 1.2<br>21 | nA |
| | $I_{COM(off)}$ | | Room<br>Full | - 1.2<br>- 21 | | 1.2<br>21 | nA |
| Channel-On Leakage Current | $I_{COM(on)}$ | V+ = 5.5 V, V+ = 5.5 V<br>$V_{NO}$, $V_{NC}$ = $V_{COM}$ = 1 V/4.5 V | Room<br>Full | - 1.2<br>- 21 | | 1.2<br>21 | nA |
| **Digital Control** | | | | | | | |
| Input High Voltage | $V_{INH}$ | | Full | 2.4 | | | V |
| Input Low Voltage | $V_{INL}$ | | Full | | | 0.8 | V |
| Input Capacitance | $C_{in}$ | | Full | | 5 | | pF |
| Input Current | $I_{INL}$ or $I_{INH}$ | $V_{IN}$ = 0 or V+ | Full | - 1 | | 1 | µA |
| **Dynamic Characteristics** | | | | | | | |
| Turn-On Time[d] | $t_{ON}$ | $V_{NO}$ or $V_{NC}$ = 3 V, $R_L$ = 300 Ω, $C_L$ = 35 pF<br>Figures 1 and 2 | Room<br>Full | | 24 | 36<br>39 | ns |
| Turn-Off Time[d] | $t_{OFF}$ | | Room<br>Full | | 9 | 22<br>25 | ns |
| Break-Before-Make Time[d] | $t_d$ | | Room | 1 | 15 | | ns |
| Charge Injection[d] | $Q_{INJ}$ | $C_L$ = 1 nF, $V_{GEN}$ = 0 V, $R_{GEN}$ = 0 Ω, Figure 3 | Room | | 38 | | pC |
| Off-Isolation[d] | OIRR | $R_L$ = 50 Ω, $C_L$ = 5 pF, f = 1 MHz | Room | | - 61 | | dB |
| Crosstalk[d] | $X_{TALK}$ | | Room | | - 67 | | dB |
| Source-Off Capacitance[d] | $C_{NO(off)}$ $C_{NC(off)}$ | $V_{IN}$ = 0 or V+, f = 1 MHz | Room | | 30 | | pF |
| Channel-On Capacitance[d] | $C_{ON}$ | | Room | | 96 | | pF |
| **Power Supply** | | | | | | | |
| Power Supply Range | V+ | | | 4.5 | | 5.5 | V |
| Power Supply Current | I+ | $V_{IN}$ = 0 or V+ | | | 0.1 | 1.0 | µA |
| Power Consumption | $P_C$ | | | | | 5.5 | µW |

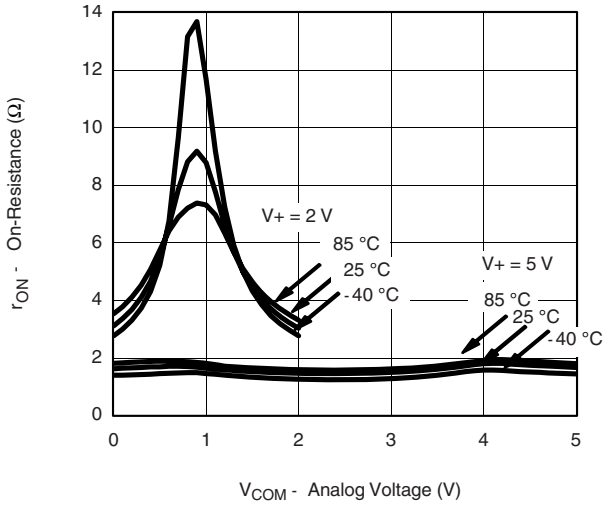
Notes:
a. Room = 25 °C, Full = as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, nor subjected to production test.
e. $V_{IN}$ = input voltage to perform proper function.
f. Guaranteed by 5 V leakage testing, not production tested.

*Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

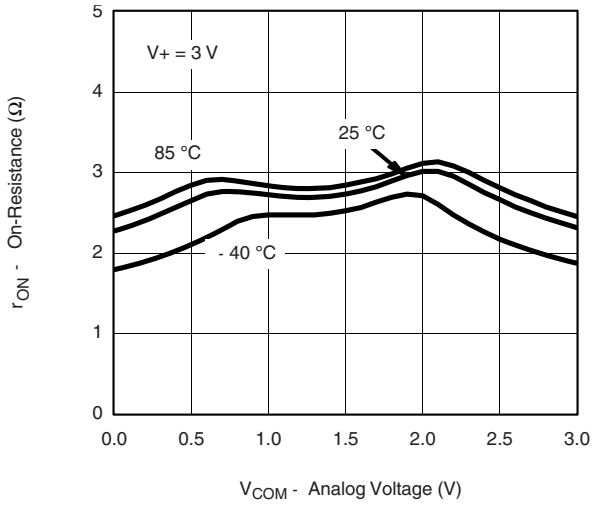
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



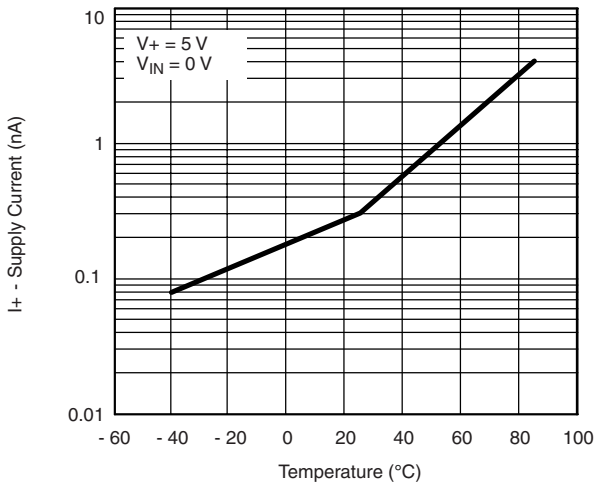

**$r_{ON}$ vs. $V_{COM}$ and Supply Voltage**



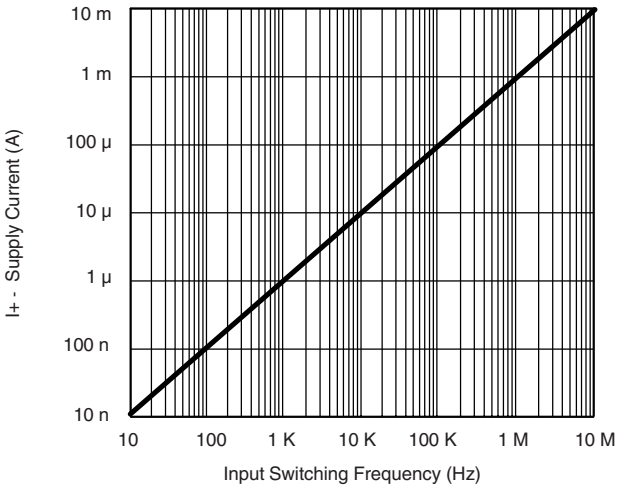

**$r_{ON}$ vs. Analog Voltage and Temperature**




**$r_{ON}$ vs. Analog Voltage and Temperature**

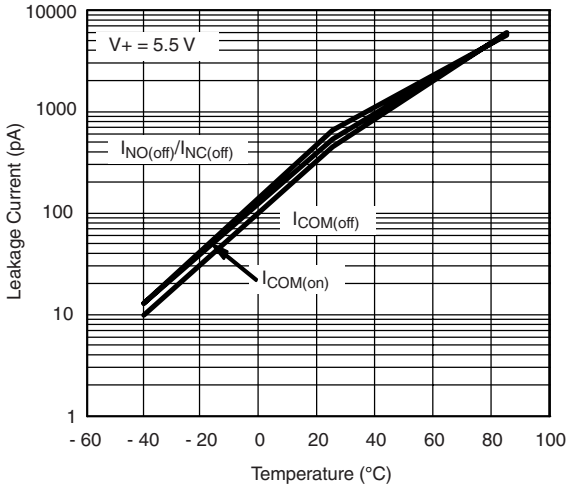



**Supply Current vs. Temperature**

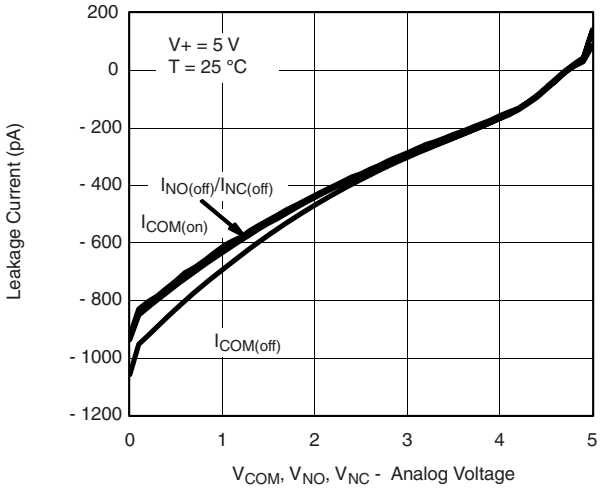



**Supply Current vs. Input Switching Frequency**

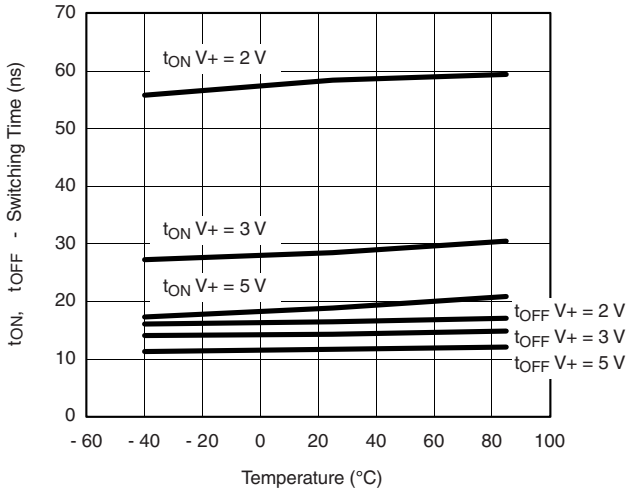
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



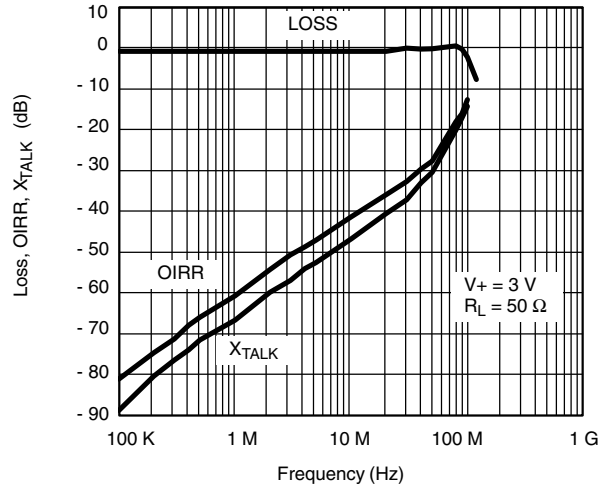

**Leakage Current vs. Temperature**



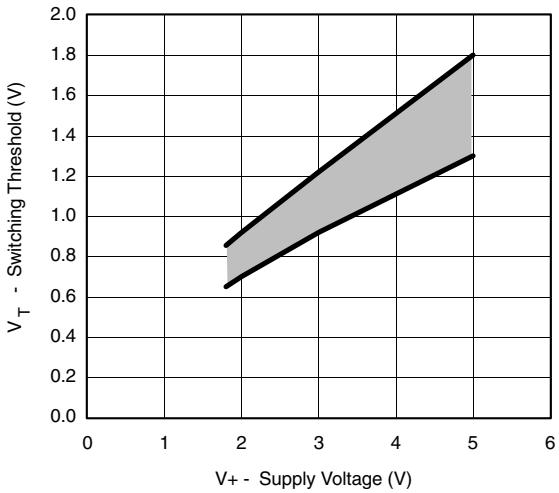

**Leakage vs. Analog Voltage**



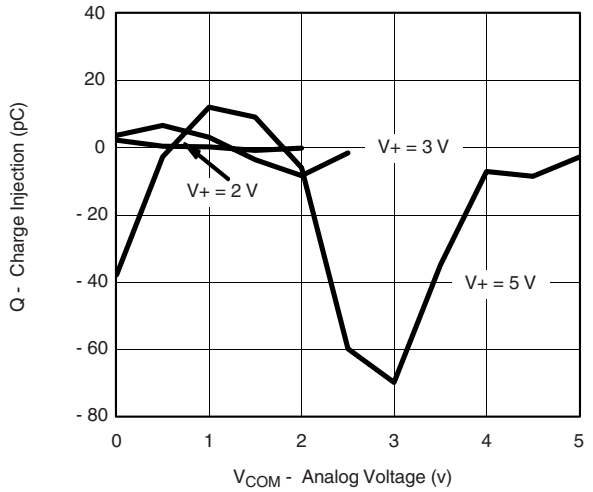

**Switching Time vs. Temperature and Supply Voltage**




**Insertion Loss, Off-Isolation, Crosstalk vs. Frequency**

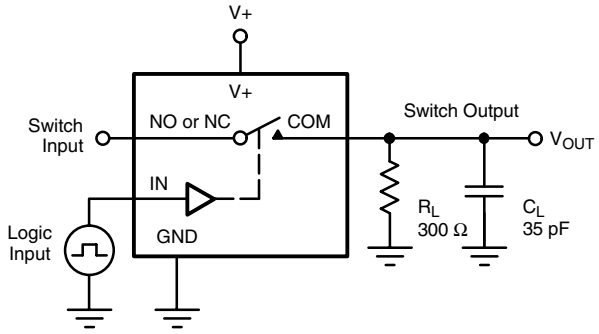



**Switching Threshold vs. Supply Voltage**



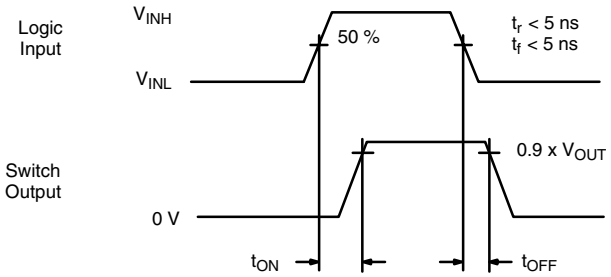

**Charge Injection vs. Analog Voltage**

## TEST CIRCUITS



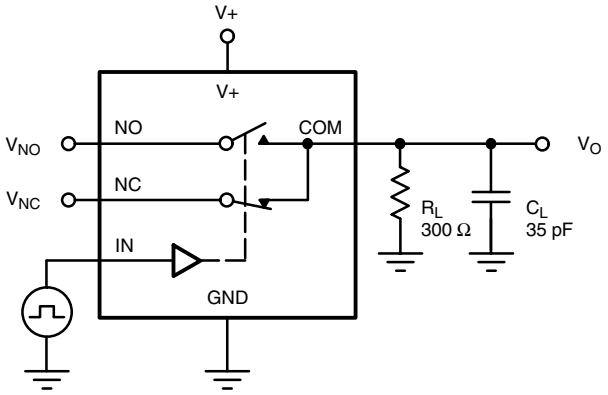

$C_L$ (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM}\left(\frac{R_L}{R_L + R_{ON}}\right)$$




Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

**Figure 1. Switching Time**




$C_L$ (includes fixture and stray capacitance)

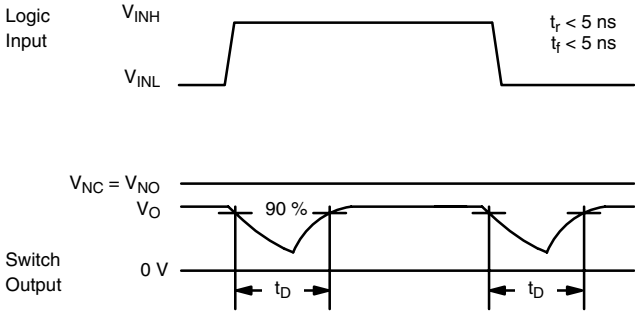
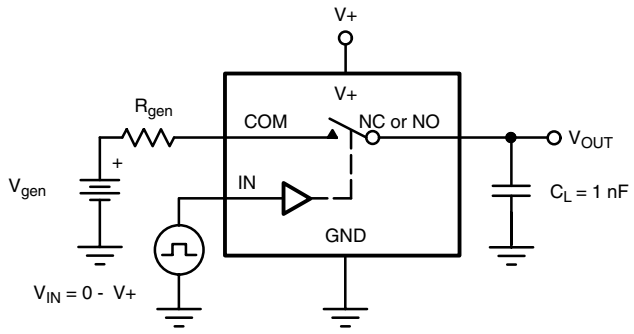
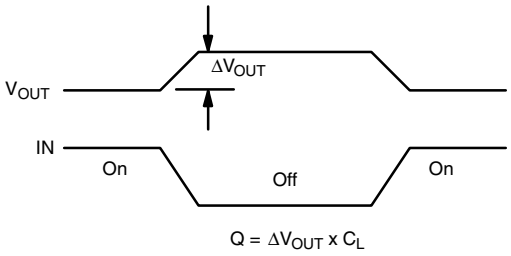



**Figure 2. Break-Before-Make Interval**




$Q = \Delta V_{OUT} \times C_L$

IN depends on switch configuration: input polarity determined by sense of switch.

**Figure 3. Charge Injection**

## TEST CIRCUITS

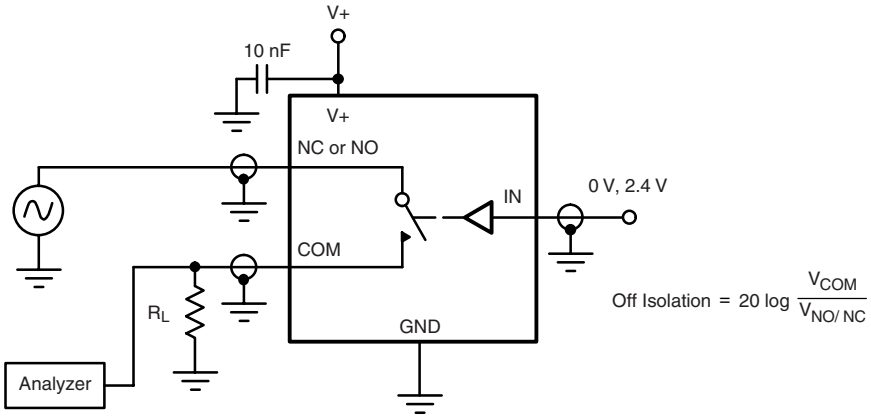



**Figure 4. Off-Isolation**

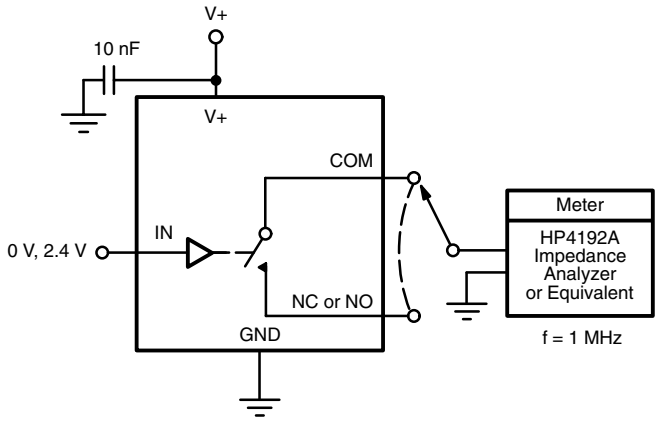
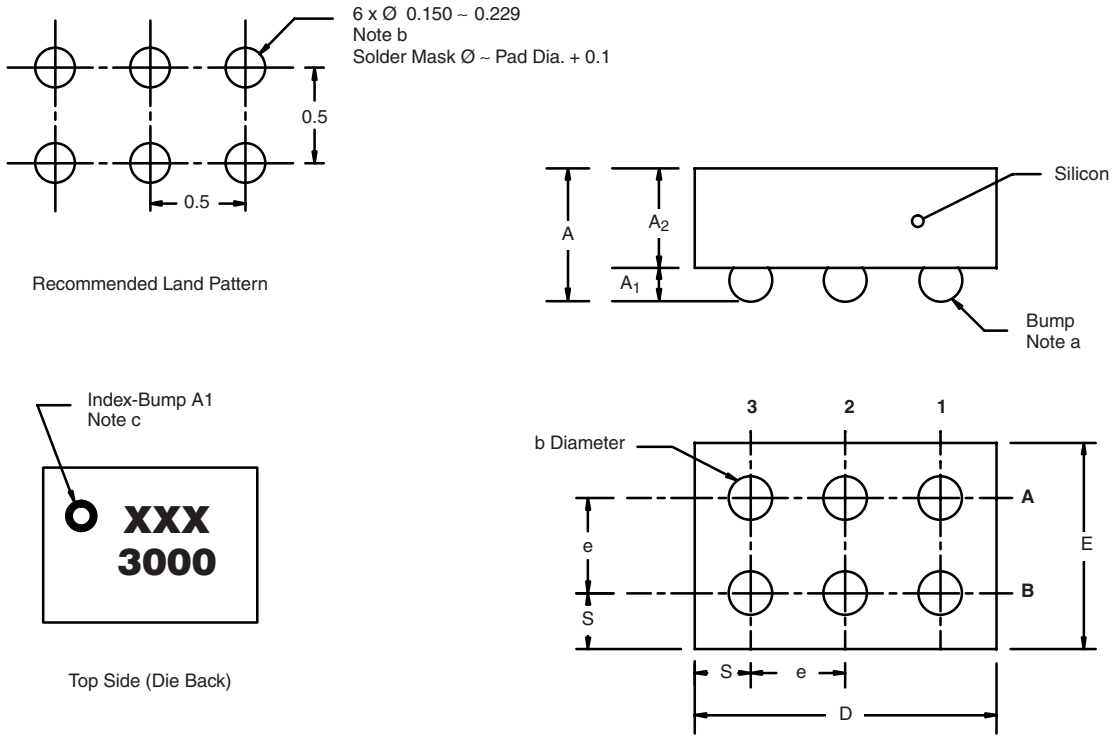



**Figure 5. Channel Off/On Capacitance**

## PACKAGE OUTLINE

### MICRO FOOT: 6-BUMP (3 x 2, 0.5 mm PITCH)




Notes (Unless Otherwise Specified):
a. Bump is Eutectic 63/57 Sn/Pb or Lead (Pb)-free Sn/Ag/Cu.
b. Non-solder mask defined copper landing pad.
c. Laser Mark on silicon die back; no coating. Shown is not actual marking; sample only.

| EUTECTIC (Sn/Pb) | | | | |
|---|---|---|---|---|
| | Millimeters[a] | | Inches | |
| Dim | Min | Max | Min | Max |
| A | 0.615 | 0.715 | 0.0242 | 0.0281 |
| $A_1$ | 0.140 | 0.190 | 0.0055 | 0.0075 |
| $A_2$ | 0.470 | 0.495 | 0.0185 | 0.0195 |
| b | 0.180 | 0.250 | 0.0071 | 0.0098 |
| D | 1.555 | 1.585 | 0.0612 | 0.0624 |
| E | 1.055 | 1.085 | 0.0415 | 0.0427 |
| e | 0.5 BASIC | | 0.0197 BASIC | |
| S | 0.278 | 0.293 | 0.0109 | 0.0115 |

Notes:
a. Use millimeters as the primary measurement.

| LEAD (Pb)-FREE (Sn/Ag/Cu) | | | | |
|---|---|---|---|---|
| | Millimeters[a] | | Inches | |
| Dim | Min | Max | Min | Max |
| A | 0.688 | 0.753 | 0.0271 | 0.0296 |
| $A_1$ | 0.218 | 0.258 | 0.0086 | 0.0102 |
| $A_2$ | 0.470 | 0.495 | 0.0185 | 0.0195 |
| b | 0.306 | 0.346 | 0.0120 | 0.0136 |
| D | 1.555 | 1.585 | 0.0612 | 0.0624 |
| E | 1.055 | 1.085 | 0.0415 | 0.0427 |
| e | 0.5 BASIC | | 0.0197 BASIC | |
| S | 0.278 | 0.293 | 0.0109 | 0.0115 |

Notes:
a. Use millimeters as the primary measurement.

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